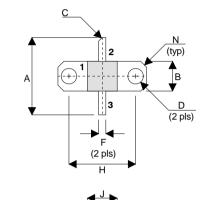
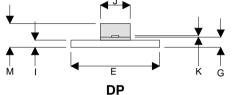


#### METAL GATE RF SILICON FET

#### **MECHANICAL DATA**





PIN<sub>2</sub>

DRAIN

PIN 1 SOURCE

PIN<sub>3</sub> **GATE** 

DIM	mm	l ol.	Inches	l ol.
Α	16.51	0.25	0.650	0.010
В	6.35	0.13	0.250	0.005
С	45°	5°	45°	5°
D	3.30	0.13	0.130	0.005
Е	18.92	0.08	0.745	0.003
F	1.52	0.13	0.060	0.005
G	2.16	0.13	0.085	0.005
Н	14.22	0.08	0.560	0.003
	1.52	0.13	0.060	0.005
J	6.35	0.13	0.250	0.005
K	0.13	0.03	0.005	0.001
М	5.08	0.51	0.200	0.020
N	1.27 x 45°	0.13	0.050 x 45°	0.005

# **GOLD METALLISED MULTI-PURPOSE SILICON DMOS RF FET** 20W - 28V - 500MHzSINGLE ENDED

#### **FEATURES**

- SIMPLIFIED AMPLIFIER DESIGN
- SUITABLE FOR BROAD BAND APPLICATIONS
- · LOW Cree
- USEFUL P<sub>O</sub> AT 1GHz
- LOW NOISE
- HIGH GAIN 13 dB MINIMUM

#### **APPLICATIONS**

 HE/VHF/UHF COMMUNICATIONS from 1 MHz to 1 GHz

### **ABSOLUTE MAXIMUM RATINGS** (T<sub>case</sub> = 25°C unless otherwise stated)

$\overline{P_D}$	Power Dissipation	50W
$BV_DSS$	Drain – Source Breakdown Voltage	70V
$BV_GSS$	Gate – Source Breakdown Voltage	±20V
I <sub>D(sat)</sub>	Drain Current	5A
T <sub>stg</sub>	Storage Temperature	−65 to 150°C
T <sub>i</sub>	Maximum Operating Junction Temperature	200°C

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#### **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub> = 25°C unless otherwise stated)

Parameter		Test Conditions		Min.	Тур.	Max.	Unit
RV	Drain-Source	V <sub>GS</sub> = 0	I <sub>D</sub> = 100mA	70			V
BV <sub>DSS</sub>	Breakdown Voltage	v <sub>GS</sub> = 0	ID = 100IIIA	70			V
I <sub>DSS</sub>	Zero Gate Voltage	\/ 29\/	V <sub>GS</sub> = 0			1	mA
	Drain Current	$V_{DS} = 28V$				ı	IIIA
I <sub>GSS</sub>	Gate Leakage Current	V <sub>GS</sub> = 20V	V <sub>DS</sub> = 0			1	μА
V <sub>GS(th)</sub>	Gate Threshold Voltage*	I <sub>D</sub> = 10mA	$V_{DS} = V_{GS}$	1		7	V
9 <sub>fs</sub>	Forward Transconductance*	V <sub>DS</sub> = 10V	I <sub>D</sub> = 1A	0.8			S
G <sub>PS</sub>	Common Source Power Gain	P <sub>O</sub> = 20W		13			dB
η	Drain Efficiency	V <sub>DS</sub> = 28V	$I_{DQ} = 0.2A$	50			%
VSWR	Load Mismatch Tolerance	f = 500MHz		20:1			_
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 28V	$V_{GS} = -5V$ $f = 1MHz$			60	pF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = 28V	$V_{GS} = 0$ $f = 1MHz$			30	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	V <sub>DS</sub> = 28V	$V_{GS} = 0$ $f = 1MHz$			2.5	pF

<sup>\*</sup> Pulse Test: Pulse Duration = 300  $\mu s$ , Duty Cycle  $\leq 2\%$ 

#### HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

#### THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE.

#### THERMAL DATA

R <sub>THj-case</sub>	Thermal Resistance Junction – Case	Max. 3.5°C / W
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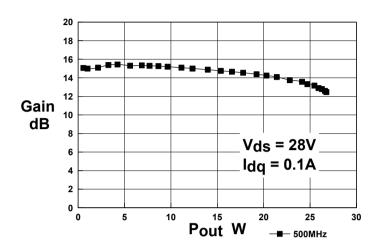
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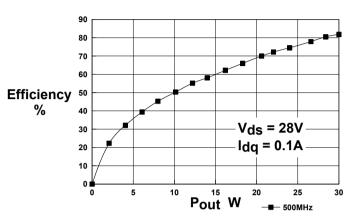


Figure 1 Gain vs. Output Power

Figure 2 Efficiency vs. Output Power

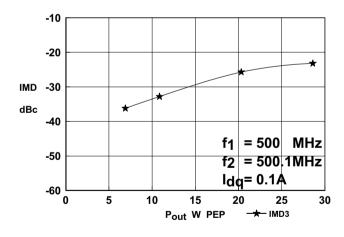


Figure 3 IMD vs. Output Power

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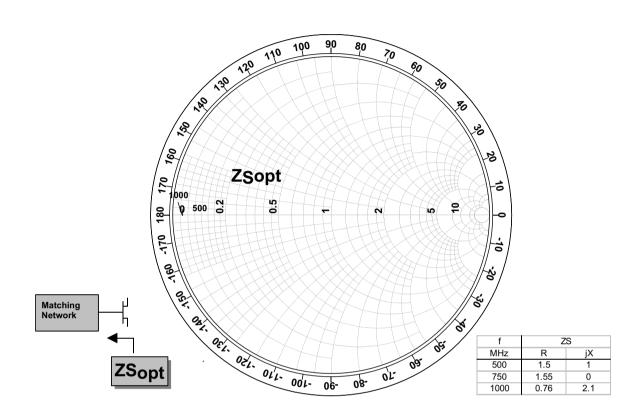
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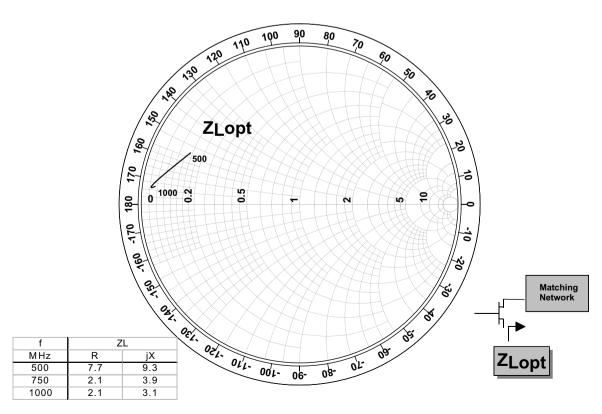
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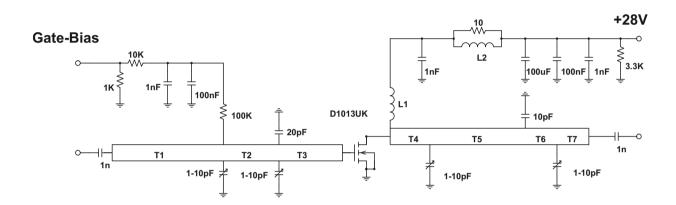
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### **500MHz Test Fixture**

Substrate 0.8 mm FR4, Er = 2.2All microstrip lines W = 2.2mm

T1 35mm

T2 15mm

T3 10mm

T4 14mm

**T5** 30mm

**T6** 6mm

**T7** 12.5mm

5.5 turns 20swg enamelled copper wire 7mm i.d. L1

1.5 turns 24swg enamelled copper wire on Siemens B62152A7X 2 hole L2

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